



SYNSEMI SEMICONDUCTOR

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Components Industries, LLC** for  
**Zener Technology and Products.**

## 500 mW DO-35 Hermetically Sealed Glass Zener Voltage Regulators

### Maximum Ratings (Note 1)

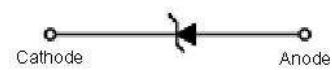
Rating	Symbol	Value	Unit
Maximum Steady State Power Dissipation @ $T_L \leq 75^\circ\text{C}$ , Lead Length = 3/8"	$P_D$	500	mW
Derate Above $75^\circ\text{C}$		4.0	mW/ $^\circ\text{C}$
Operating and Storage Temperature Range	$T_J, T_{sg}$	-65 to +200	$^\circ\text{C}$

1. Some part number series have lower JEDEC registered ratings.



### Specification Features

- Zener Voltage Range = 6.8 V to 75 V
- ESD Rating of Class 3 (>16 KV) per Human Body Model
- DO-35 Package (DO-204AH)
- Double Slug Type Construction
- Metallurgical Bonding



### Mechanical Characteristics

**Case** : Double slug type, hermetically sealed glass

**Finish** : All external surfaces are corrosion resistant and leads are readily solderable.

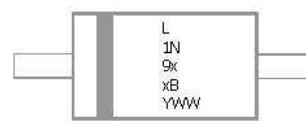
**Polarity** : Cathode indicated by polarity band.

**Mounting:** Any

### Maximum Lead Temperature for Soldering Purposes

230°C, 1/16" from the case for 10 seconds

### MARKING DIAGRAM



L = Logo  
 1N = Device Code  
 Y = Year  
 WW = Work Week

### Ordering Information

Device	Package	Shipping
1N9xxB	Axial Lead	3000 Units / Box
1N9xBRL	Axial Lead	5000 Units / Tape & Reel
1N9xBRL2*	Axial Lead	5000 Units / Tape & Reel
1N9xBRA1 <i>I</i>	Lead Form	3000 Units / Radial Tape & Ammo
1N9xBRA2 <i>I</i>	Lead Form	3000 Units / Radial Tape & Ammo
1N9xBTA	Axial Lead	5000 Units / Tape & Ammo
1N9xBTA2*	Axial Lead	5000 Units / Tape & Ammo
1N9xBRR1 <i>I</i>	Lead Form	3000 Units / Radial Tape & Reel
1N9xBRR2 <i>I</i>	Lead Form	3000 Units / Radial Tape & Reel

\* The "2" suffix refers to 26 mm tape spacing.

*I* Polarity band **up** with cathode lead off first.

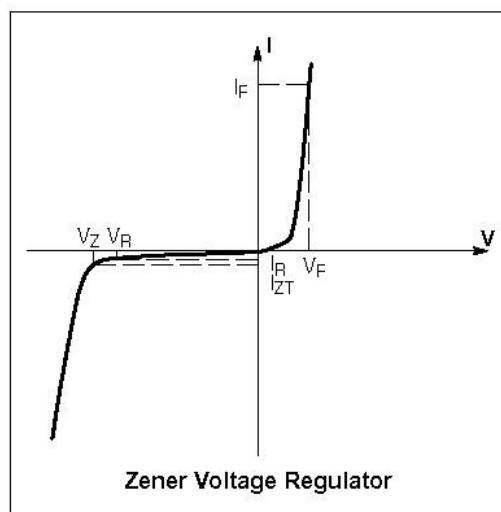
*i* Polarity band **down** with cathode lead off first.

Devices listed in **bold italic** are Synsemi **Preferred** devices. **Preferred** devices are recommended choices for future use and best overall value.

# 1N957B Series

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted,  $V_F = 1.5 \text{ V Max} @ I_F = 200 \text{ mA}$  for all types)

Symbol	Parameter
$V_Z$	Reverse Zener Voltage @ $I_{ZT}$
$I_{ZT}$	Reverse Current
$Z_{ZT}$	Maximum Zener Impedance @ $I_{ZT}$
$I_{ZK}$	Reverse Current
$Z_{ZK}$	Maximum Zener Impedance @ $I_{ZK}$
$I_R$	Reverse Leakage Current @ $V_R$
$V_R$	Breakdown Voltage
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$
$I_{ZM}$	Maximum DC Zener Current



**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted,  $V_F = 1.5 \text{ V Max} @ I_F = 200 \text{ mA}$  for all types)

Device (Note 2.)	Device Marking	Zener Voltage (Note 3.)				Zener Impedance (Note 4.)		Leakage Current		$I_{ZM}$ (Note 5.)	
		V <sub>Z</sub> (Volts)		@ I <sub>ZT</sub>		Z <sub>ZT</sub> @ I <sub>ZT</sub>	Z <sub>ZK</sub> @ I <sub>ZK</sub>	I <sub>R</sub> @ V <sub>R</sub>			
		Min	Nom	Max	mA			mA	A	Volts	mA
1N957B	1N957B	6.46	6.8	7.14	18.5	4.5	700	1.0	150	5.2	47
1N958B	1N958B	7.125	7.5	7.875	16.5	5.5	700	0.5	75	5.7	42
1N959B	1N959B	7.79	8.2	8.61	15	6.5	700	0.5	50	6.2	38
1N960B	1N960B	8.645	9.1	9.555	14	7.5	700	0.5	25	6.9	35
1N961B	1N961B	9.5	10	10.5	12.5	8.5	700	0.25	10	7.6	32
1N962B	1N962B	10.45	11	11.55	11.5	9.5	700	0.25	5	8.4	28
1N963B	1N963B	11.4	12	12.6	10.5	11.5	700	0.25	5	9.1	26
1N964B	1N964B	12.35	13	13.65	9.5	13	700	0.25	5	9.9	24
1N965B	1N965B	14.25	15	15.75	8.5	16	700	0.25	5	11.4	21
1N966B	1N966B	15.2	16	16.8	7.8	17	700	0.25	5	12.2	19
1N967B	1N967B	17.1	18	18.9	7.0	21	750	0.25	5	13.7	17
1N968B	1N968B	19	20	21	6.2	25	750	0.25	5	15.2	15
1N969B	1N969B	20.9	22	23.1	5.6	29	750	0.25	5	16.7	14
1N970B	1N970B	22.8	24	25.2	5.2	33	750	0.25	5	18.2	13
1N971B	1N971B	25.65	27	28.35	4.6	41	750	0.25	5	20.6	11
1N972B	1N972B	28.5	30	31.5	4.2	49	1000	0.25	5	22.8	10
1N973B	1N973B	31.35	33	34.65	3.8	58	1000	0.25	5	25.1	9.2
1N974B	1N974B	34.2	36	37.8	3.4	70	1000	0.25	5	27.4	8.5
1N975B	1N975B	37.05	39	40.95	3.2	80	1000	0.25	5	29.7	7.8
1N978B	1N978B	48.45	51	53.55	2.5	125	1500	0.25	5	38.8	5.9
1N979B	1N979B	53.2	56	58.8	2.2	150	2000	0.25	5	42.6	5.4
1N982B	1N982B	71.25	75	78.75	1.7	270	2000	0.25	5	56	4.1

## 2. TOLERANCE AND VOLTAGE DESIGNATION

Tolerance designation - Device tolerance of  $\pm 5\%$  is indicated by a "B" suffix.

## 3. ZENER VOLTAGE ( $V_Z$ ) MEASUREMENT

Nominal zener voltage is measured with the device junction in the thermal equilibrium at the lead temperature ( $T_L$ ) at  $30^\circ\text{C} \pm 1^\circ\text{C}$  and  $3/8"$  lead length.

## 4. ZENER IMPEDANCE ( $Z_Z$ ) DERIVATION

$Z_{ZT}$  and  $Z_{ZK}$  are measured by dividing the ac voltage drop across the device by the ac current applied. The specified limits are for  $I_{Z(ac)} = 0.1 I_{Z(dc)}$  with the ac frequency = 60 Hz.

## 5. MAXIMUM ZENER CURRENT RATINGS ( $I_{ZM}$ )

Values shown are based on the JEDEC rating of 400 mW where the actual zener voltage ( $V_Z$ ) is known at the operating point, the maximum zener current may be increased and is limited by the derating curve.

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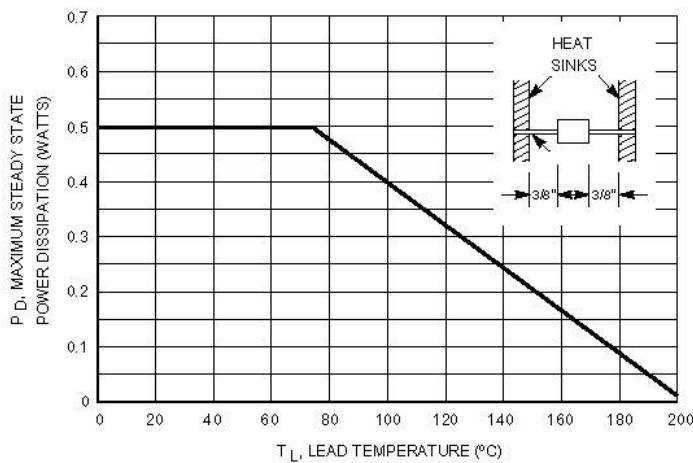


Figure 1. Steady State Power Derating

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## APPLICATION NOTE - ZENER VOLTAGE

Since the actual voltage available from a given zener diode is temperature dependent, it is necessary to determine junction temperature under any set of operating conditions in order to calculate its value. The following procedure is recommended:

Lead Temperature,  $T_L$ , should be determined from:

$$T_L = \theta_{LA} P_D + T_A$$

$\theta_{LA}$  is the lead-to-ambient thermal resistance ( $^{\circ}\text{C/W}$ ) and  $P_D$  is the power dissipation. The value for  $\theta_{LA}$  will vary and depends on the device mounting method.  $\theta_{LA}$  is generally 30 to  $40^{\circ}\text{C/W}$  for the various clips and tie points in common use and for printed circuit board wiring.

The temperature of the lead can also be measured using a thermocouple placed on the lead as close as possible to the tie point. The thermal mass connected to the tie point is normally large enough so that it will not significantly respond to heat surges generated in the diode as a result of pulsed operation once steady-state conditions are achieved. Using the measured value of  $T_L$ , the junction temperature may be determined by:

$$T_J = T_L + \Delta T_{JL}$$

$\Delta T_{JL}$  is the increase in junction temperature above the lead temperature and may be found from Figure 2 for dc power:

$$\Delta T_{JL} = \theta_{JL} P_D$$

For worst-case design, using expected limits of  $I_Z$ , limits of  $P_D$  and the extremes of  $T_J(\Delta T_J)$  may be estimated. Changes in voltage,  $V_Z$ , can then be found from:

$$\Delta V = \theta_{VZ} T_J$$

$\theta_{VZ}$ , the zener voltage temperature coefficient, is found from Figures 4 and 5.

Under high power-pulse operation, the zener voltage will vary with time and may also be affected significantly by the zener resistance. For best regulation, keep current excursions as low as possible.

Surge limitations are given in Figure 7. They are lower than would be expected by considering only junction temperature, as current crowding effects cause temperatures to be extremely high in small spots, resulting in device degradation should the limits of Figure 7 be exceeded.

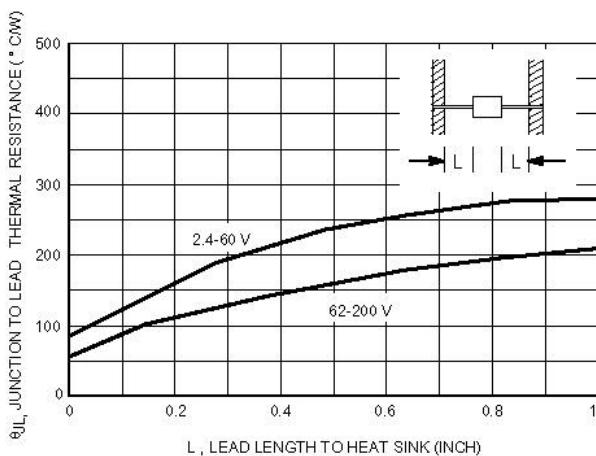


Figure 2. Typical Thermal Resistance

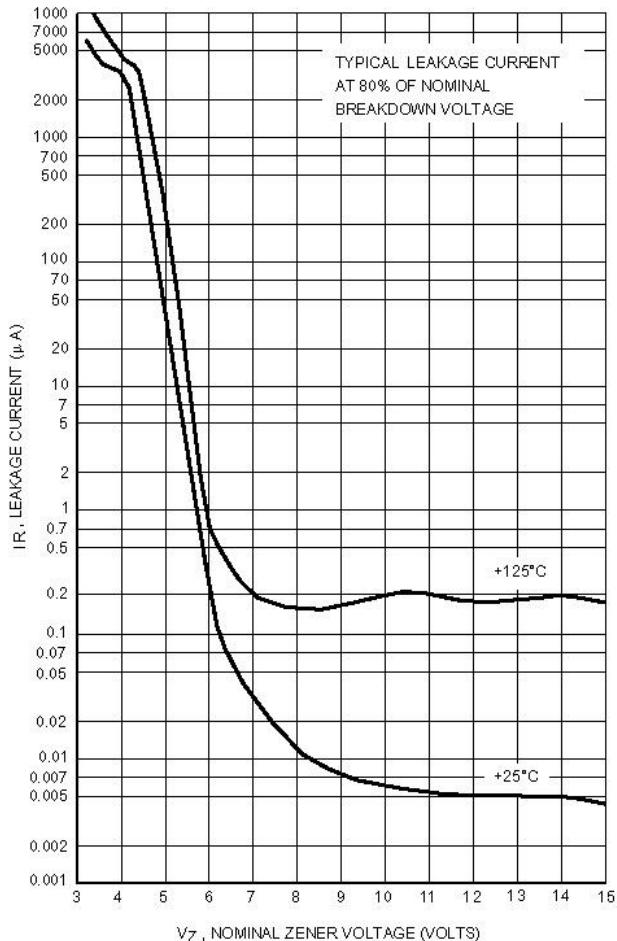


Figure 3. Typical Leakage Current

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## TEMPERATURE COEFFICIENTS

(-55°C to +150°C temperature range; 90% of the units are in the ranges indicated.)

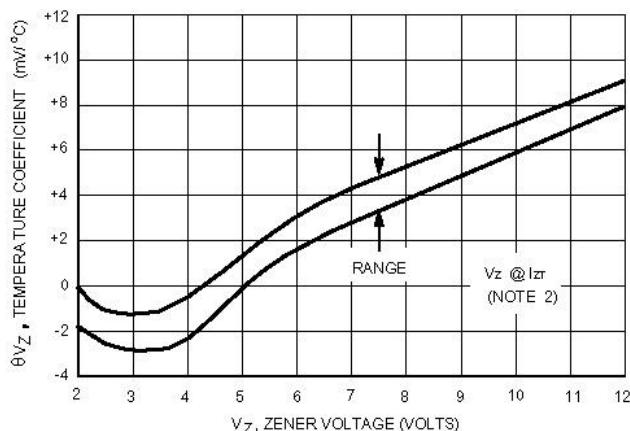


Figure 4a. Range for Units to 12 Volts

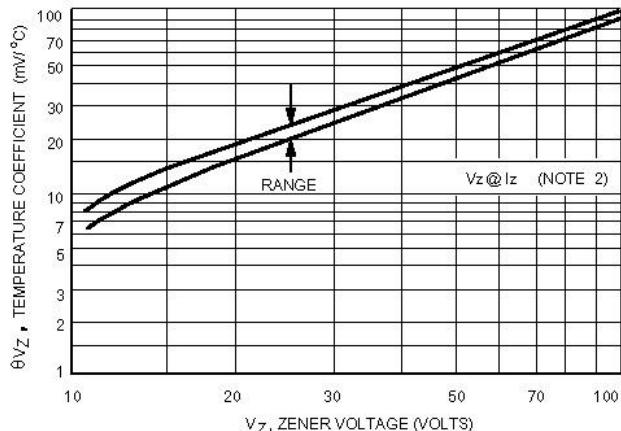


Figure 4b. Range for Units 12 to 100 Volts

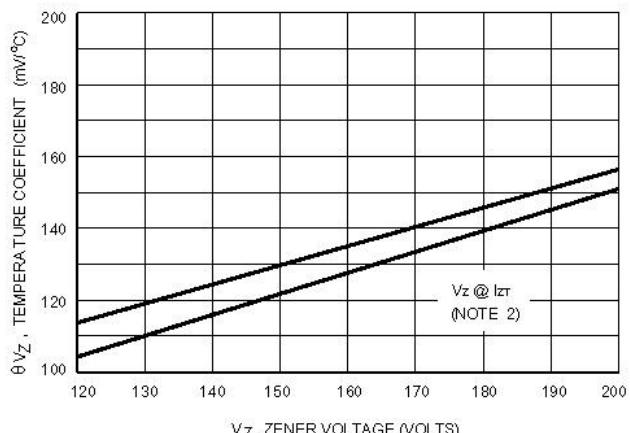


Figure 4c. Range for Units 120 to 200 Volts

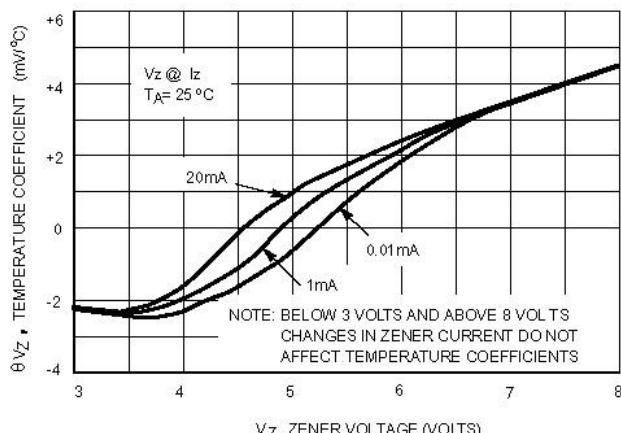


Figure 5. Effect of Zener Current

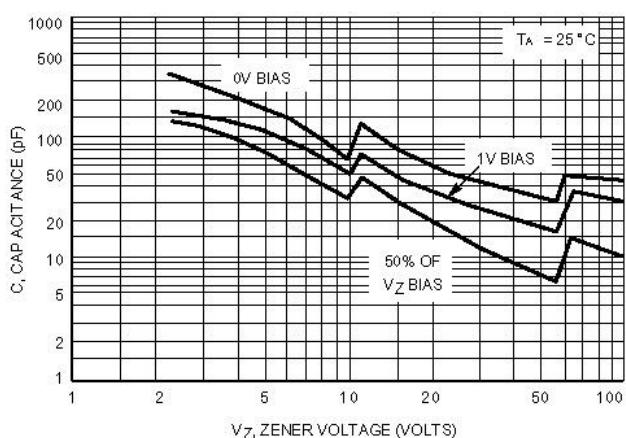


Figure 6a. Typical Capacitance 2.4-100 Volts

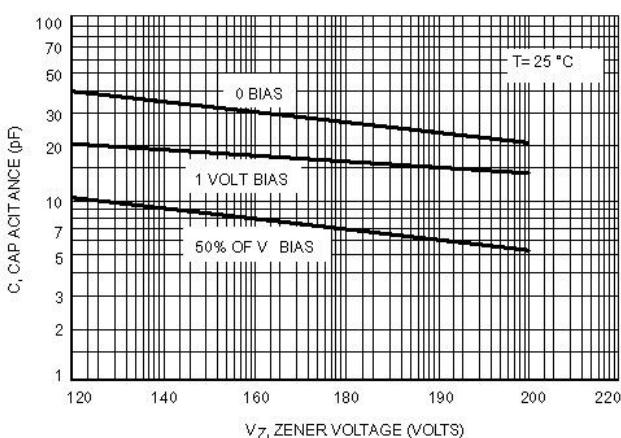


Figure 6b. Typical Capacitance 120-200 Volts

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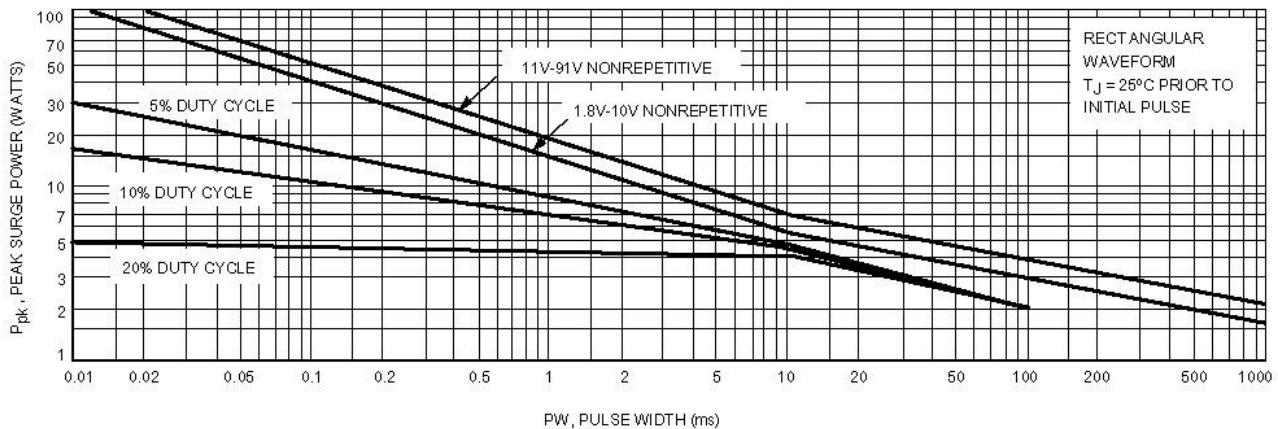


Figure 7a. Maximum Surge Power 1.8-91 Volts

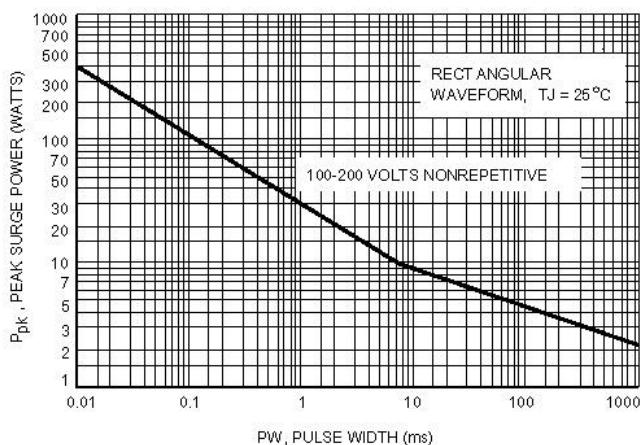


Figure 7b. Maximum Surge Power DO-35  
100-200Volts

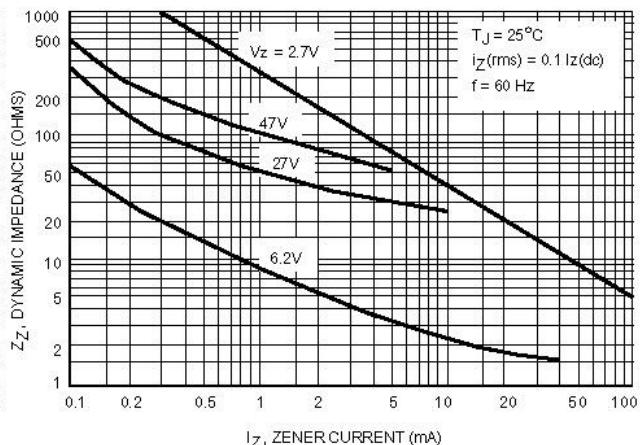


Figure 8. Effect of Zener Current on  
Zener Impedance

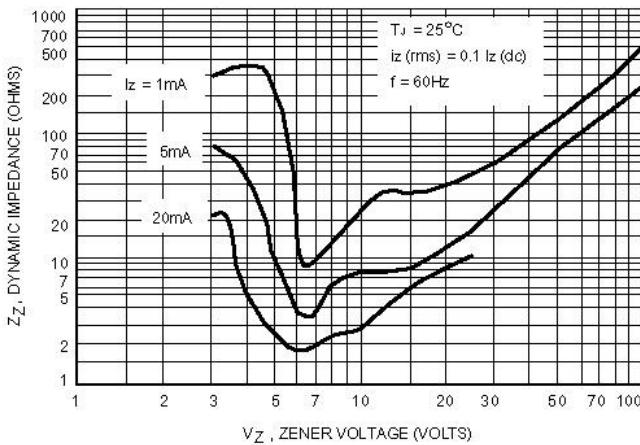


Figure 9. Effect of Zener Voltage on Zener Impedance

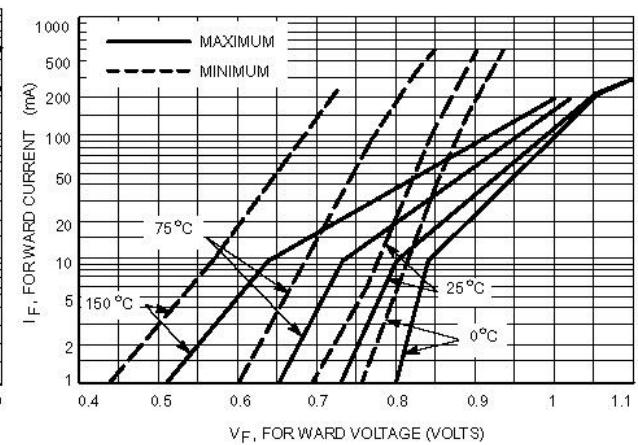


Figure 10. Typical Forward Characteristics

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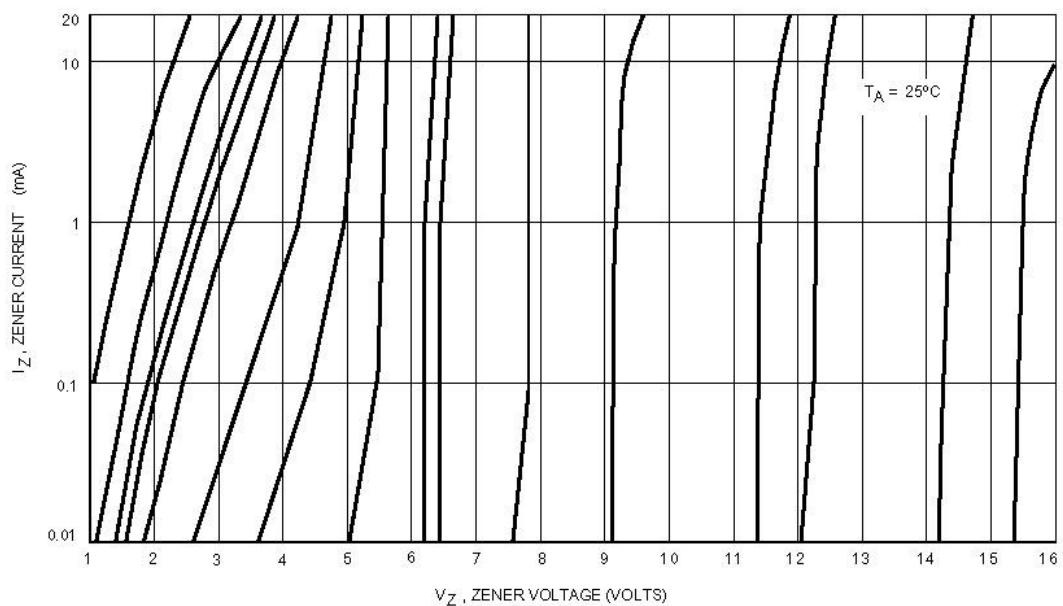


Figure 1. Zener Voltage versus Zener Current -  $V_Z$  = 1 thru 16 Volts

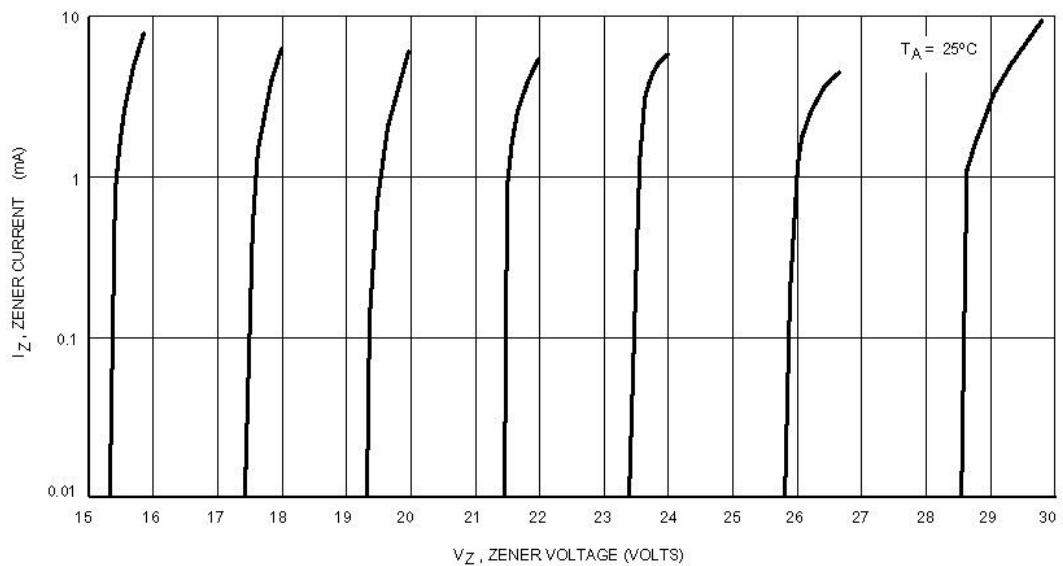


Figure 12. Zener Voltage versus Zener Current -  $V_Z$  = 15 thru 30 Volts

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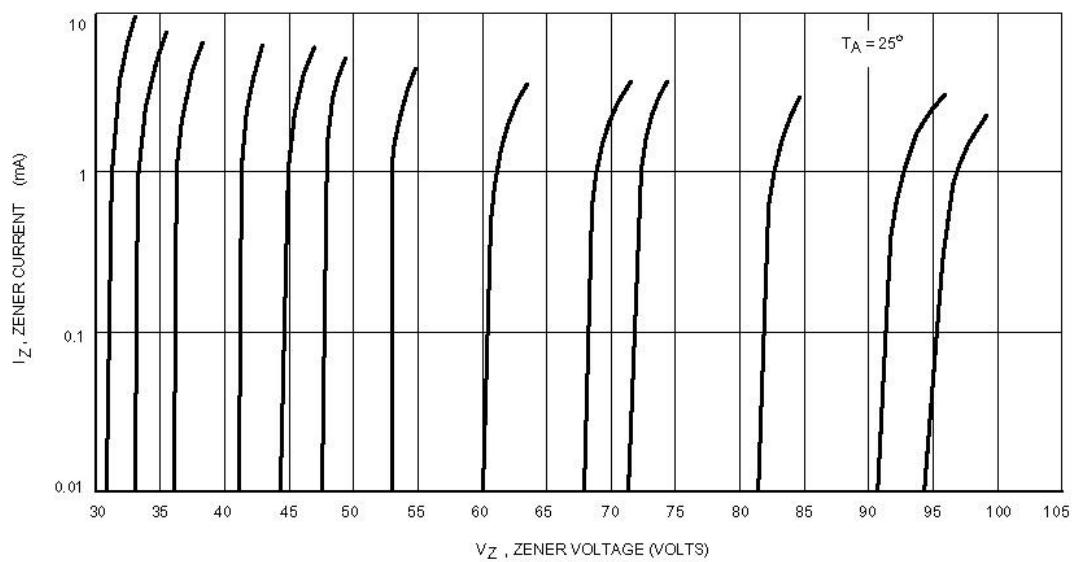


Figure 13. Zener Voltage versus Zener Current -  $V_Z$  = 30 thru 105 Volts

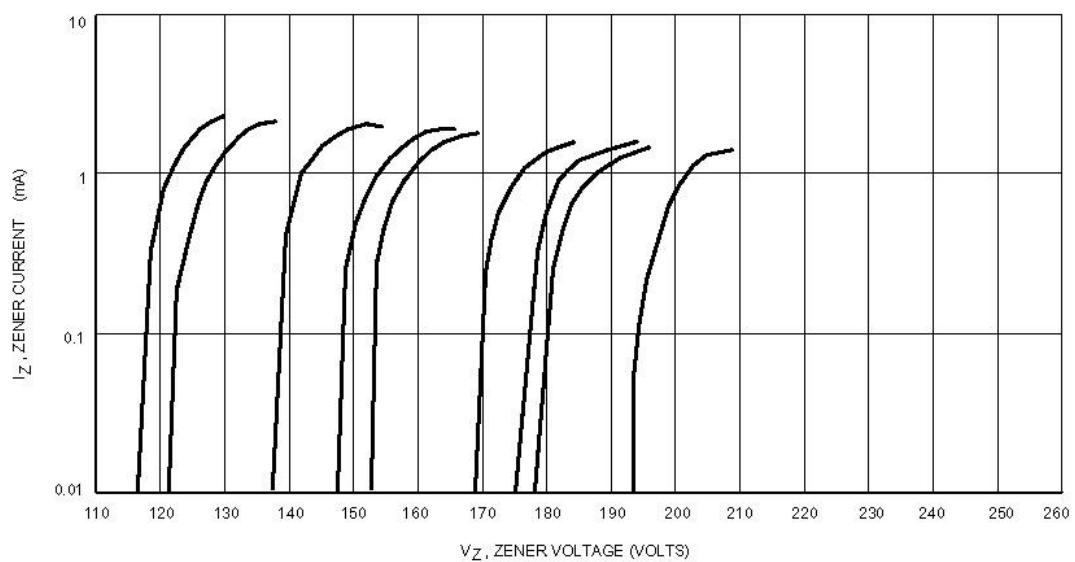


Figure 14. Zener Voltage versus Zener Current -  $V_Z$  = 110 thru 220 Volts